



Description

The DMG6968UDM uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 20V, I_D = 7A$

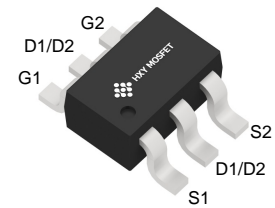
$R_{DS(ON)} < 20m\Omega @ V_{GS}=4.5V$

Application

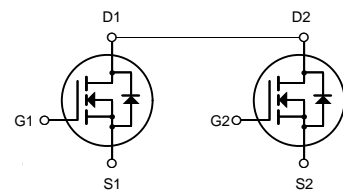
Battery protection

Load switch

Power management



SOT-23-6L
(SOT-26)



Dual N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
DMG6968UDM	SOT-23-6L(SOT-26)	HXY MOSFET	3000

Absolute Maximum Ratings@ $T_J=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	20	V
V_{GS}	Gate-Source Voltage	± 10	V
$I_D @ T_A=25^\circ\text{C}$	Drain Current, $V_{GS} @ 4.5V^3$	7	A
I_{DM}	Pulsed Drain Current ¹	25	A
$P_D @ T_A=25^\circ\text{C}$	Total Power Dissipation	1.25	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$
R_{thj-a}	Maximum Thermal Resistance, Junction-ambient ³	100	$^\circ\text{C/W}$



Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V,V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	0.5	0.7	1.2	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =4.5A	-	14	20	mΩ
		V _{GS} =2.5V, I _D =3.5A	-	19	25	mΩ
Forward Transconductance	g _{FS}	V _{DS} =5V,I _D =4.5A	-	10	-	S
Dynamic Characteristics						
Input Capacitance	C _{ISS}	V _{DS} =10V,V _{GS} =0V, F=1.0MHz	-	900	-	PF
Output Capacitance	C _{OSS}		-	220	-	PF
Reverse Transfer Capacitance	C _{RSS}		-	100	-	PF
Switching Characteristics						
Turn-on Delay Time	t _{d(on)}	V _{DD} =10V,I _D =1A V _{GS} =4.5V,R _{GEN} =6Ω	-	10	20	nS
Turn-on Rise Time	t _r		-	11	25	nS
Turn-Off Delay Time	t _{d(off)}		-	35	70	nS
Turn-Off Fall Time	t _f		-	30	60	nS
Total Gate Charge	Q _g	V _{DS} =10V,I _D =6A, V _{GS} =4.5V	-	12	15	nC
Gate-Source Charge	Q _{gs}		-	2.3	-	nC
Gate-Drain Charge	Q _{gd}		-	1	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage ^(Note 3)	V _{SD}	V _{GS} =0V,I _S =1.7A	-	0.75	1.2	V
Diode Forward Current ^(Note 2)	I _S		-	-	6.5	A



Typical Electrical and Thermal Characteristics

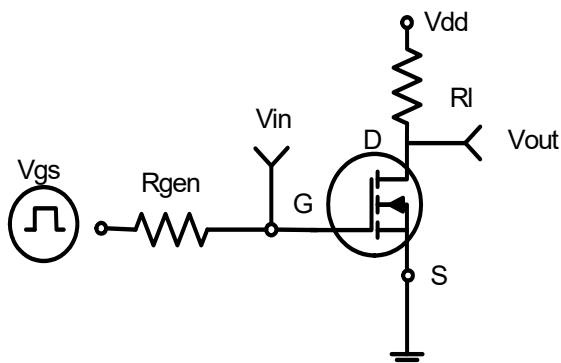


Figure 1: Switching Test Circuit

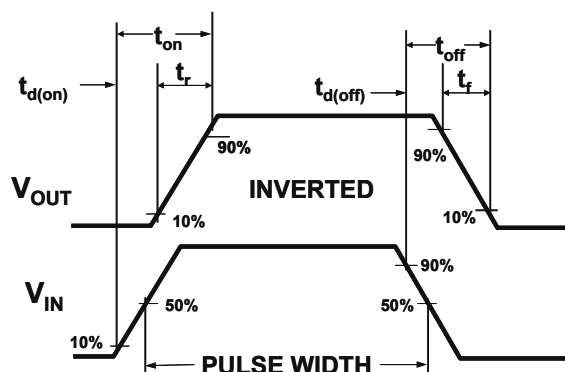


Figure 2: Switching Waveforms

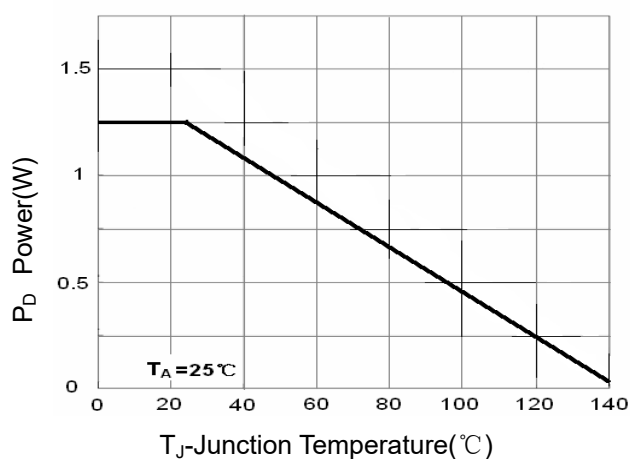


Figure 3 Power Dissipation

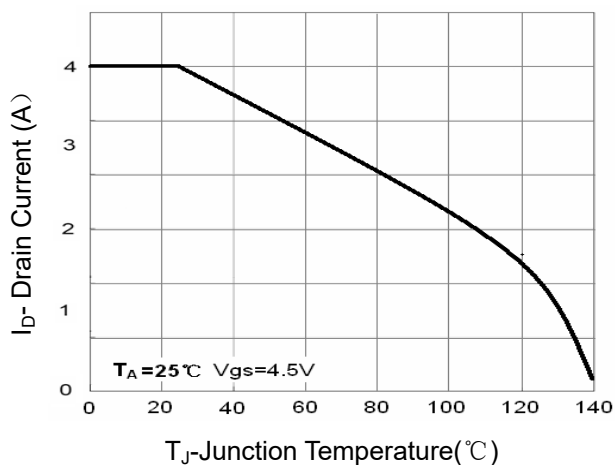


Figure 4 Drain Current

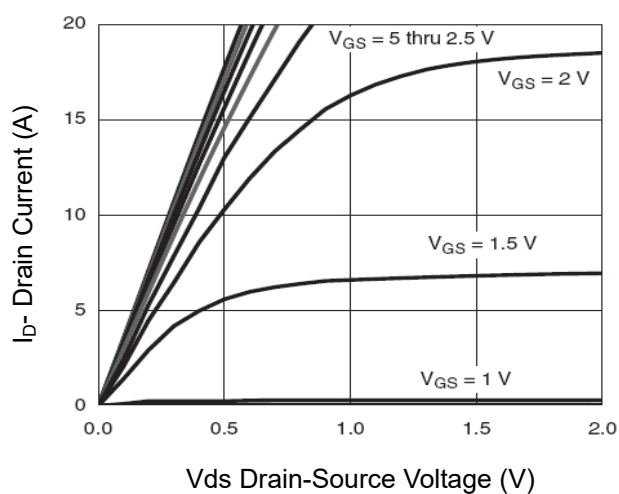


Figure 5 Output Characteristics

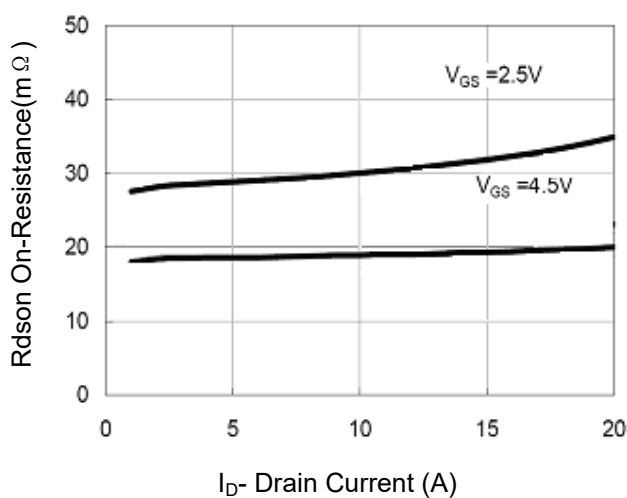


Figure 6 Drain-Source On-Resistance

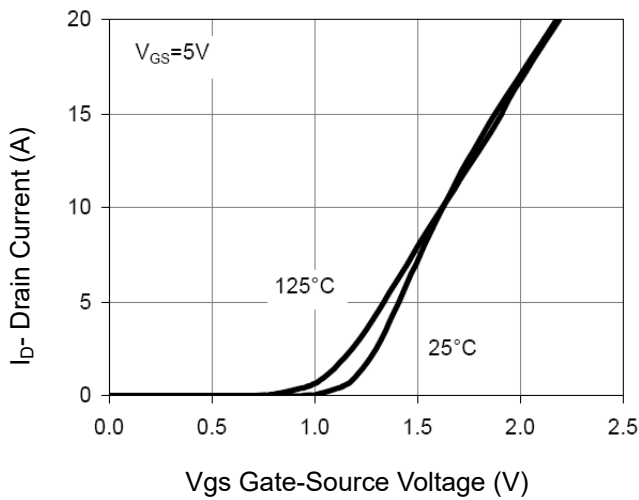


Figure 7 Transfer Characteristics

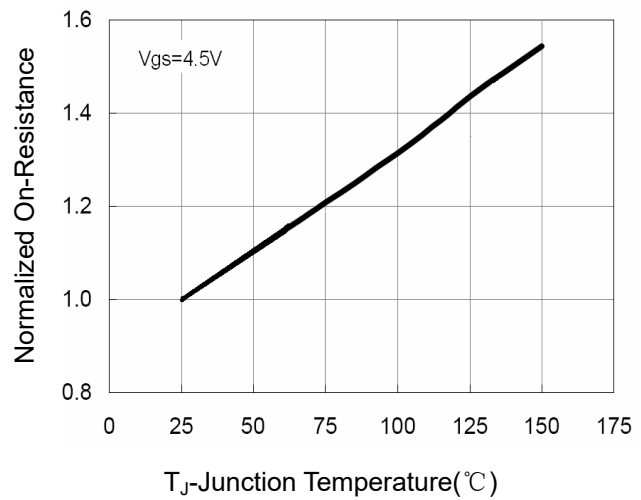


Figure 8 Drain-Source On-Resistance

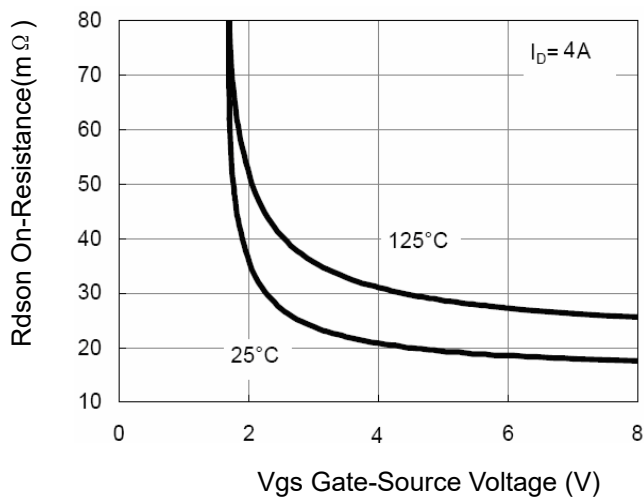


Figure 9 Rdson vs Vgs

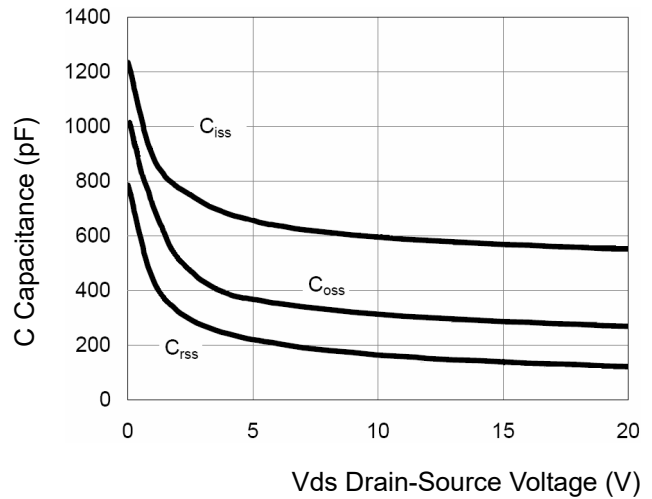


Figure 10 Capacitance vs Vds

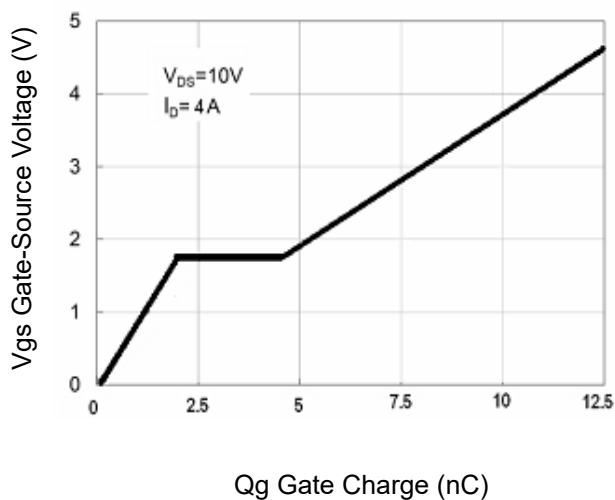


Figure 11 Gate Charge

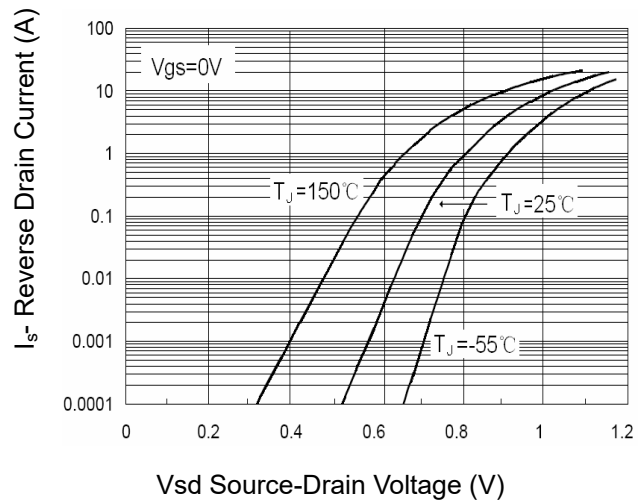


Figure 12 Source- Drain Diode Forward

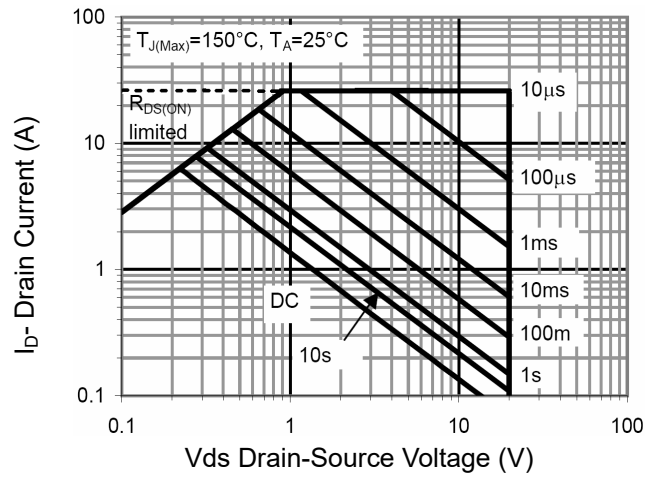


Figure 13 Safe Operation Area

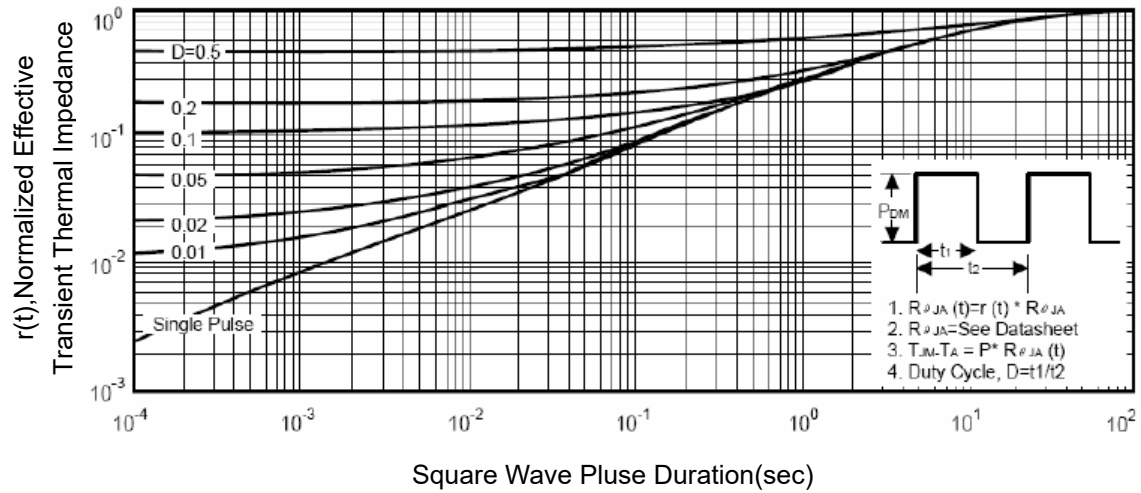
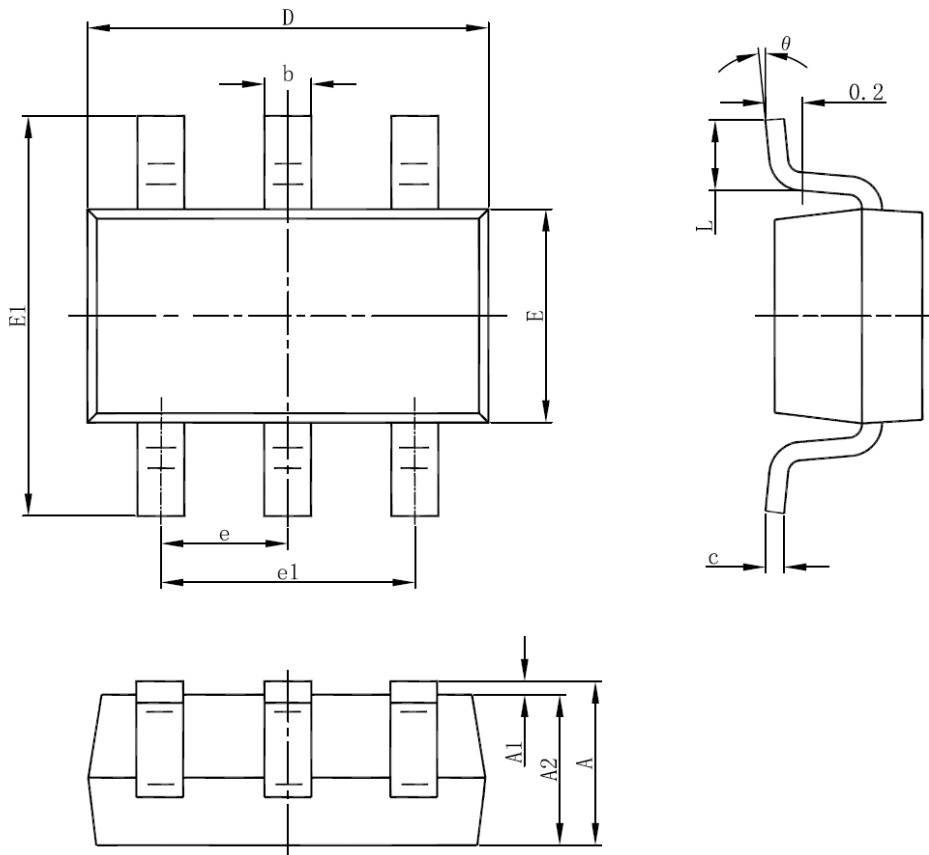


Figure 14 Normalized Maximum Transient Thermal Impedance



SOT-23-6L(SOT-26) Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



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